# THE DATASHEET OF

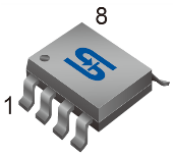
# TSM600P03CS RLG

# TSM600P03CS

30V P-Channel Power MOSFET

Pb-Free RoHS COMPLIANT

**SOP-8**




**Pin Definition:**

1. Source
2. Source
3. Source
4. Gate
8. Drain
7. Drain
6. Drain
5. Drain

## Key Parameter Performance

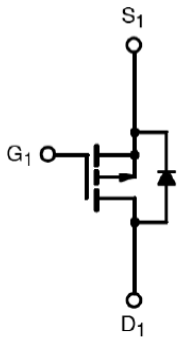
| Parameter | | Value | Unit |
|---|---|---|---|
| $V_{DS}$ | | -30 | V |
| $R_{DS(on)}$(max) | $V_{GS}$=-10V | 60 | mΩ |
| | $V_{GS}$=-4.5V | 90 | |
| $Q_g$ | | 5.1 | nC |

## Ordering Information

| Part No. | Package | Packing |
|---|---|---|
| TSM600P03CS RLG | SOP-8 | 2.5kps / 13'' Reel |

**Note:** "G" denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

## Block Diagram




P-Channel MOSFET

## Absolute Maximum Ratings (Tc = 25°C unless otherwise noted)

| Parameter | | Symbol | Limit | Unit |
|---|---|---|---|---|
| Drain-Source Voltage | | $V_{DS}$ | -30 | V |
| Gate-Source Voltage | | $V_{GS}$ | ±20 | V |
| Continuous Drain Current* | Tc = 25ºC | $I_D$ | -4.7 | A |
| | Tc = 100ºC | | -3 | A |
| Pulsed Drain Current (Note 1) | | $I_{DM}$ | -18.8 | A |
| Power Dissipation @ $T_C$ = 25°C | | $P_D$ | 2.1 | W |
| Operating Junction and Storage Temperature Range | | $T_J$, $T_{STG}$ | -55 to +150 | °C |

## Thermal Performance

| Parameter | Symbol | Limit | Unit |
|---|---|---|---|
| Thermal Resistance - Junction to Ambient | $R_{\Theta JA}$ | 50 | °C/W |

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30V P-Channel Power MOSFET

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## Electrical Specifications ($T_J$ = 25°C unless otherwise noted)

| Parameter | Conditions | Symbol | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| **Static** | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS}$ = 0V, $I_D$ = 250μA | $BV_{DSS}$ | -30 | -- | -- | V |
| Drain-Source On-State Resistance | $V_{GS}$ = -10V, $I_D$ = -3A | $R_{DS(ON)}$ | -- | 44 | 60 | mΩ |
| | $V_{GS}$ = -4.5V, $I_D$ = -2A | | | 73 | 90 | |
| Gate Threshold Voltage | $V_{DS}$ = $V_{GS}$, $I_D$ = 250μA | $V_{GS(TH)}$ | -1.2 | -1.6 | -2.5 | V |
| Zero Gate Voltage Drain Current | $V_{DS}$ = -30V, $T_J$ = 25ºC | $I_{DSS}$ | -- | -- | -1 | μA |
| | $V_{DS}$ = -24V, $T_J$ = 125ºC | | -- | -- | -10 | |
| Gate Body Leakage | $V_{GS}$ = ±20V, $V_{DS}$ = 0V | $I_{GSS}$ | -- | -- | ±100 | nA |
| Forward Transconductance (Note 2) | $V_{DS}$ = -10V, $I_D$ = -3A | $g_{fs}$ | -- | 3.5 | -- | S |
| **Dynamic** | | | | | | |
| Total Gate Charge (Note 2,3) | $V_{DS}$ = -15V, $I_D$ = -3A, $V_{GS}$ = -4.5V | $Q_g$ | -- | 5.1 | -- | nC |
| Gate-Source Charge (Note 2,3) | | $Q_{gs}$ | -- | 2 | -- | |
| Gate-Drain Charge (Note 2,3) | | $Q_{gd}$ | -- | 2.2 | -- | |
| Input Capacitance | $V_{DS}$ = -15V, $V_{GS}$ = 0V, f = 1.0MHz | $C_{iss}$ | -- | 560 | -- | pF |
| Output Capacitance | | $C_{oss}$ | -- | 55 | -- | |
| Reverse Transfer Capacitance | | $C_{rss}$ | -- | 40 | -- | |
| **Switching** | | | | | | |
| Turn-On Delay Time (Note 2,3) | $V_{DD}$ = -15V, $I_D$ = -1A, $V_{GS}$ = -10V, $R_G$ =6Ω | $t_{d(on)}$ | -- | 3.4 | -- | ns |
| Turn-On Rise Time (Note 2,3) | | $t_r$ | -- | 10.8 | -- | |
| Turn-Off Delay Time (Note 2,3) | | $t_{d(off)}$ | -- | 26.9 | -- | |
| Turn-Off Fall Time (Note 2,3) | | $t_f$ | -- | 6.9 | -- | |
| **Source-Drain Diode Ratings and Characteristic** | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | Integral reverse diode in the MOSFET | $I_S$ | -- | -- | -4.7 | A |
| Maximum Pulse Drain-Source Diode Forward Current | | $I_{SM}$ | -- | -- | -18.8 | A |
| Diode-Source Forward Voltage | $V_{GS}$ = 0V, $I_S$ = -1A | $V_{SD}$ | -- | -- | -1 | V |

**Note:**

1. Pulse width limited by safe operating area
2. Pulse test: pulse width ≤300μs, duty cycle ≤2%
3. Switching time is essentially independent of operating temperature.

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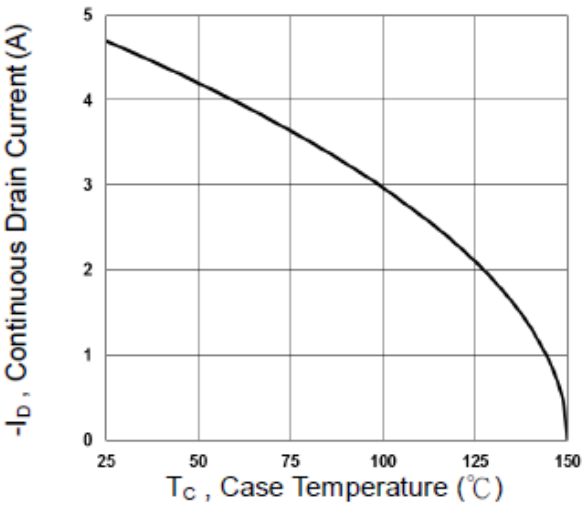
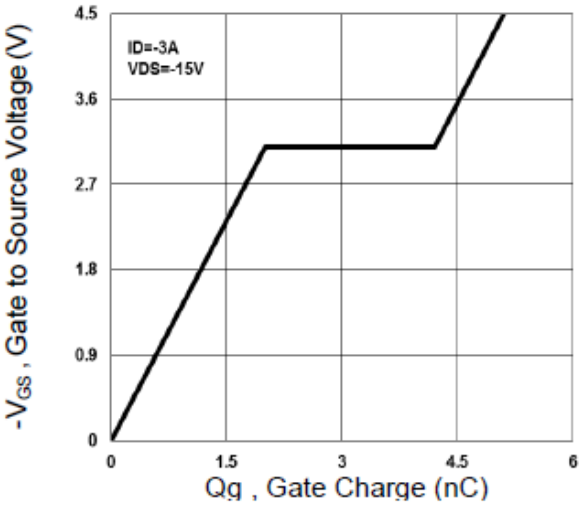
## Electrical Characteristics Curve

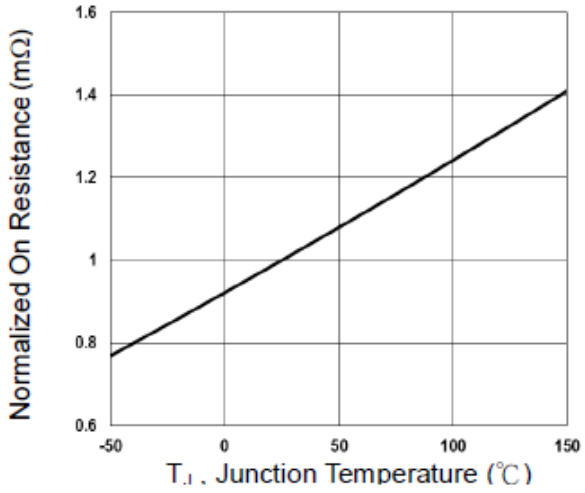
### Continuous Drain Current vs. $T_C$



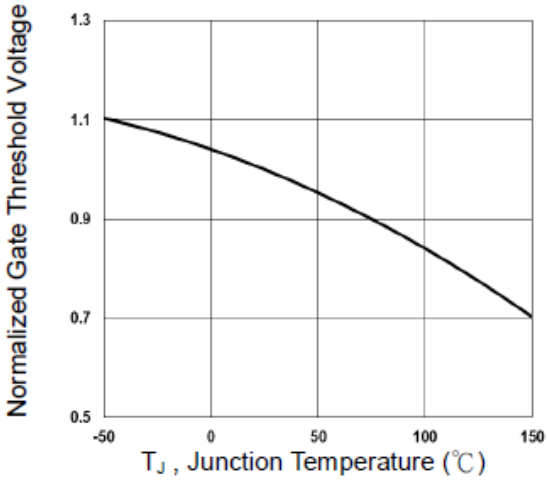

### Gate Charge



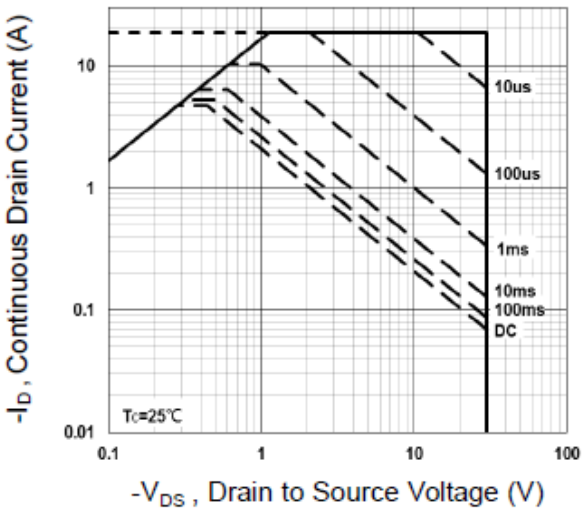

### On-Resistance vs. Junction Temperature



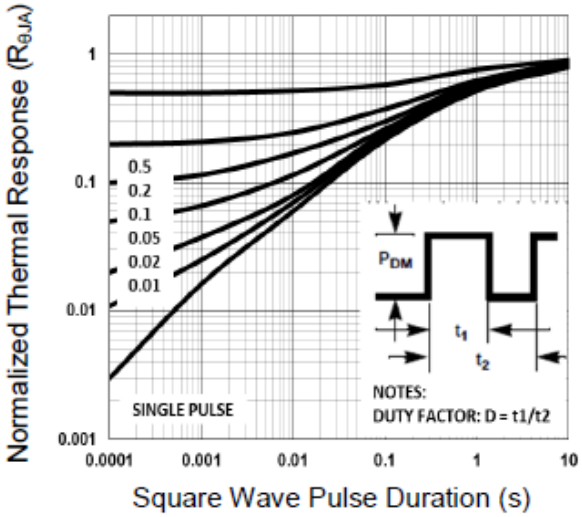

### Threshold Voltage vs. Junction Temperature




### Maximum Safe Operating Area




### Normalized Thermal Transient Impedance Curve



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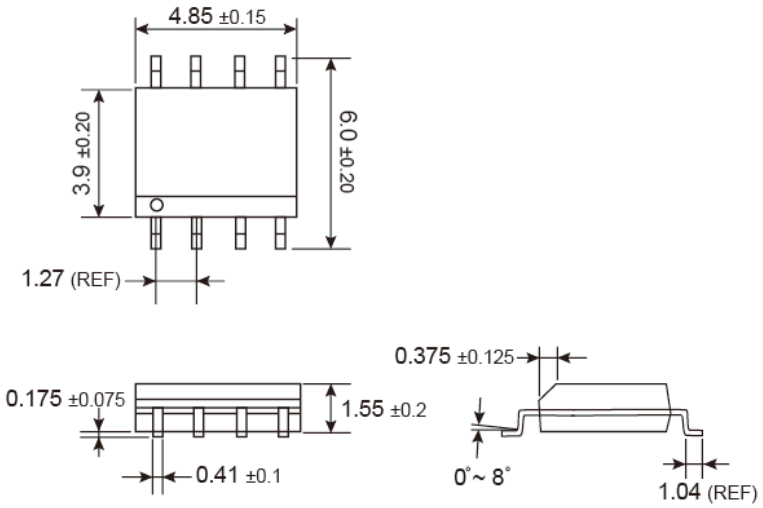
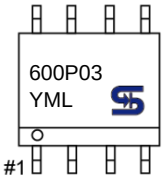
## SOP-8 Mechanical Drawing




Unit: Millimeters

## MARKING DIAGRAM




**Y** = Year Code

**M** = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apl, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)

**L** = Lot Code

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